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Enhanced Thermoelectricity in the Correlated Semiconductor FeSb₂

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Recently, FeSb₂ was classified as a new *d*-electron based correlated semiconductor [1], similar to the unique FeSi. The discoveries of a colossal thermopower amount to $S = 45$ mV/K and a huge thermoelectric power factor of $PF = S^2/\rho = 2300$ μ W/K²cm [2] near 10 K stimulate us to study the physics of the thermoelectricity enhancement and its possibility as practical thermoelectric material for low temperature cooling. In this work, we measure the thermoelectric properties of a new FeSb₂ single crystal prepared by chemical vapor transport technique, and make a comparison with the Ru-based homologue RuSb₂. Thermodynamic properties show strong indications of correlation effects in the former, while they are absent in the latter. Enhanced thermopower with a peak in excess of 10 mV/K was observed below ~ 30 K, in agreement with the previous report [2]. Together with a relatively small electrical resistivity, this leads to a large thermoelectric power factor, 650 μ W/K²cm. On the other hand, RuSb₂ shows less enhanced thermopower with small power factor. Nernst coefficient is also enhanced in FeSb₂ in the same temperature range, however, showing a very different temperature dependence from thermopower. We argue that the enhanced thermoelectricity in FeSb₂ is due to the electron-electron correlation effects which are absent in RuSb₂. Analysis based on classical models will also be presented, which shows that the dominating term in the enhanced thermopower in FeSb₂ is indeed electronic in origin.

[1] C. Petrovic *et al.*, Phys. Rev. B **72** 045103 (2005), Phys. Rev. B **67** 155205 (2003).

[2] A. Benti *et al.*, Europhys. Lett. **80** 17008 (2007).